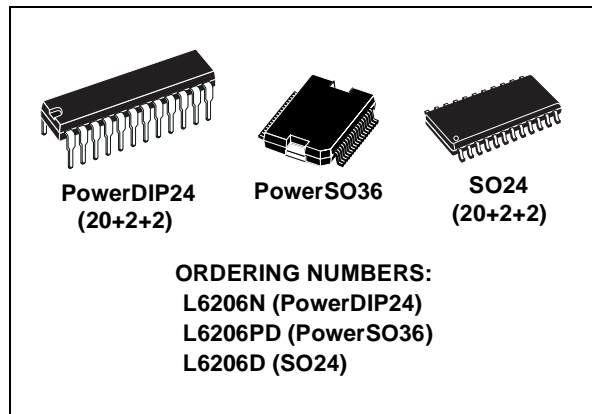


DMOS DUAL FULL BRIDGE DRIVER

- OPERATING SUPPLY VOLTAGE FROM 8 TO 52V
- 5.6A OUTPUT PEAK CURRENT (2.8A DC)
- $R_{DS(ON)}$ 0.3Ω TYP. VALUE @ $T_j = 25\text{ }^\circ\text{C}$
- OPERATING FREQUENCY UP TO 100KHz
- PROGRAMMABLE HIGH SIDE OVERCURRENT DETECTION AND PROTECTION
- DIAGNOSTIC OUTPUT
- PARALLELED OPERATION
- CROSS CONDUCTION PROTECTION
- THERMAL SHUTDOWN
- UNDER VOLTAGE LOCKOUT
- INTEGRATED FAST FREE WHEELING DIODES



TYPICAL APPLICATIONS

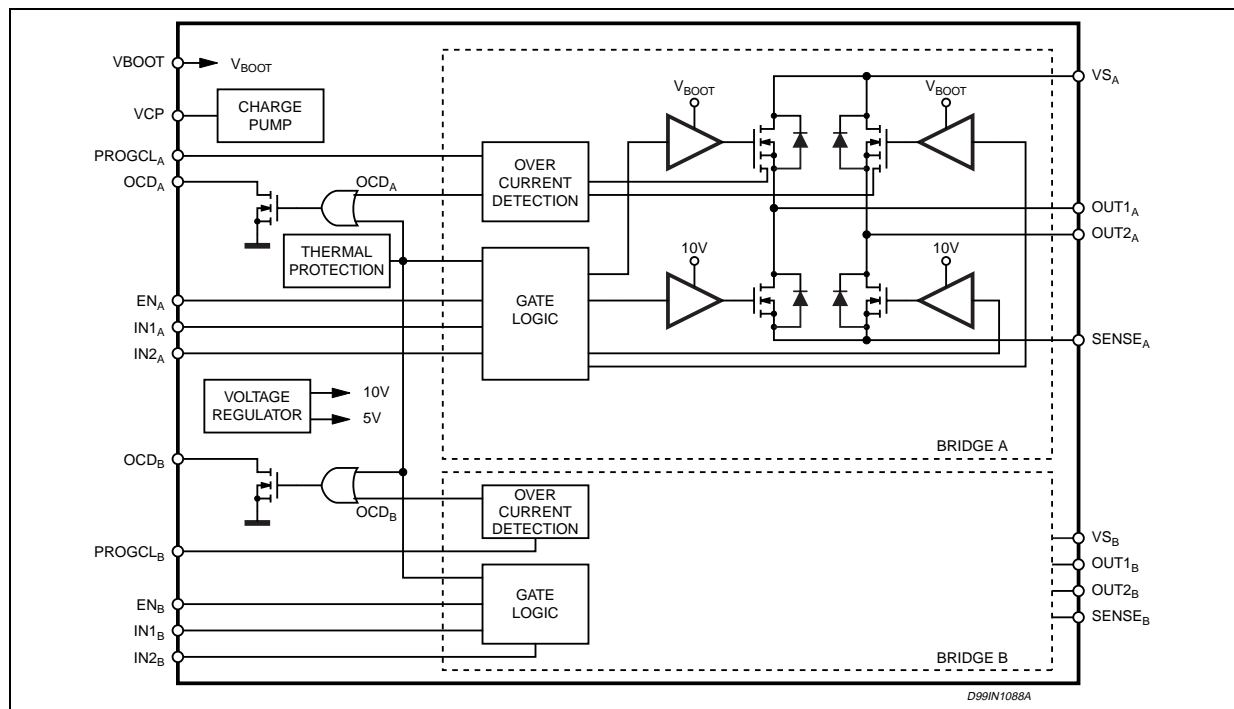
- BIPOLAR STEPPER MOTOR
- DUAL OR QUAD DC MOTOR

DESCRIPTION

The L6206 is a DMOS Dual Full Bridge designed for motor control applications, realized in MultiPower-

BCD technology, which combines isolated DMOS Power Transistors with CMOS and bipolar circuits on the same chip. Available in PowerDIP24 (20+2+2), PowerSO36 and SO24 (20+2+2) packages, the L6206 features thermal shutdown and a non-dissipative overcurrent detection on the high side Power MOSFETs plus a diagnostic output that can be easily used to implement the overcurrent protection.

BLOCK DIAGRAM



ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Test conditions	Value	Unit
V_S	Supply Voltage	$V_{SA} = V_{SB} = V_S$	60	V
V_{OD}	Differential Voltage between V_{SA} , $OUT1_A$, $OUT2_A$, $SENSE_A$ and V_{SB} , $OUT1_B$, $OUT2_B$, $SENSE_B$	$V_{SA} = V_{SB} = V_S = 60V$; $V_{SENSE_A} = V_{SENSE_B} = GND$	60	V
OCD_A, OCD_B	OCD pins Voltage Range		-0.3 to +10	V
$PROGCL_A$, $PROGCL_B$	PROGCL pins Voltage Range		-0.3 to +7	V
V_{BOOT}	Bootstrap Peak Voltage	$V_{SA} = V_{SB} = V_S$	$V_S + 10$	V
V_{IN}, V_{EN}	Input and Enable Voltage Range		-0.3 to +7	V
V_{SENSE_A} , V_{SENSE_B}	Voltage Range at pins $SENSE_A$ and $SENSE_B$		-1 to +4	V
$I_{S(peak)}$	Pulsed Supply Current (for each V_S pin), internally limited by the overcurrent protection	$V_{SA} = V_{SB} = V_S$; $t_{PULSE} < 1ms$	7.1	A
I_S	RMS Supply Current (for each V_S pin)	$V_{SA} = V_{SB} = V_S$	2.8	A
$T_{stg, TOP}$	Storage and Operating Temperature Range		-40 to 150	°C

RECOMMENDED OPERATING CONDITIONS

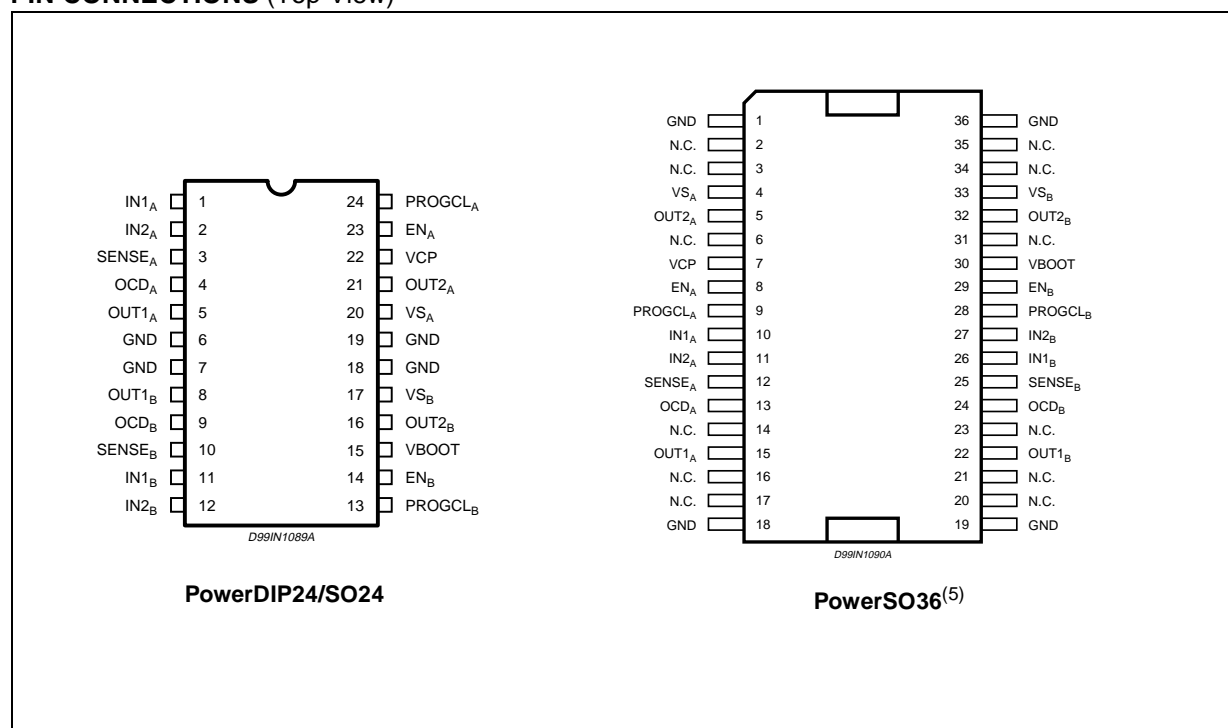
Symbol	Parameter	Test Conditions	MIN	MAX	Unit
V_S	Supply Voltage	$V_{SA} = V_{SB} = V_S$	8	52	V
V_{OD}	Differential Voltage Between V_{SA} , $OUT1_A$, $OUT2_A$, $SENSE_A$ and V_{SB} , $OUT1_B$, $OUT2_B$, $SENSE_B$	$V_{SA} = V_{SB} = V_S$; $V_{SENSE_A} = V_{SENSE_B}$		52	V
V_{SENSE_A} , V_{SENSE_B}	Voltage Range at pins $SENSE_A$ and $SENSE_B$	(pulsed $t_W < t_{rr}$) (DC)	-6 -1	6 1	V V
I_{OUT}	RMS Output Current			2.8	A
T_j	Operating Junction Temperature		-25	+125	°C
f_{sw}	Switching Frequency			100	KHz

THERMAL DATA

Symbol	Description	PowerDIP24	SO24	PowerSO36	Unit
R _{th-j-pins}	Maximum Thermal Resistance Junction-Pins	18	14	-	°C/W
R _{th-j-case}	Maximum Thermal Resistance Junction-Case	-	-	1	°C/W
R _{th-j-amb1}	Maximum Thermal Resistance Junction-Ambient ¹	43	51	-	°C/W
R _{th-j-amb1}	Maximum Thermal Resistance Junction-Ambient ²	-	-	35	°C/W
R _{th-j-amb1}	Maximum Thermal Resistance Junction-Ambient ³	-	-	15	°C/W
R _{th-j-amb2}	Maximum Thermal Resistance Junction-Ambient ⁴	58	77	62	°C/W

- (1) Mounted on a multi-layer FR4 PCB with a dissipating copper surface on the bottom side of 6 cm² (with a thickness of 35 μm).
(2) Mounted on a multi-layer FR4 PCB with a dissipating copper surface on the top side of 6 cm² (with a thickness of 35 μm).
(3) Mounted on a multi-layer FR4 PCB with a dissipating copper surface on the top side of 6 cm² (with a thickness of 35 μm), 16 via holes and a ground layer.
(4) Mounted on a multi-layer FR4 PCB without any heat sinking surface on the board.

PIN CONNECTIONS (Top View)



(5) The slug is internally connected to pins 1, 18, 19 and 36 (GND pins).

PIN DESCRIPTION

PACKAGE		Name	Type	Function
SO24/ PowerDIP24	PowerSO36			
PIN #	PIN #			
1	10	IN1 _A	Logic input	Bridge A Logic Input 1.
2	11	IN2 _A	Logic input	Bridge A Logic Input 2.
3	12	SENSE _A	Power Supply	Bridge A Source Pin. This pin must be connected to Power Ground directly or through a sensing power resistor.
4	13	OCD _A	Open Drain Output	Bridge A Overcurrent Detection and thermal protection pin. An internal open drain transistor pulls to GND when overcurrent on bridge A is detected or in case of thermal protection.
5	15	OUT1 _A	Power Output	Bridge A Output 1.
6, 7, 18, 19	1, 18, 19, 36	GND	GND	Signal Ground terminals. In Power DIP and SO packages, these pins are also used for heat dissipation toward the PCB.
8	22	OUT1 _B	Power Output	Bridge B Output 1.
9	24	OCD _B	Open Drain Output	Bridge B Overcurrent Detection and thermal protection pin. An internal open drain transistor pulls to GND when overcurrent on bridge B is detected or in case of thermal protection.
10	25	SENSE _B	Power Supply	Bridge B Source Pin. This pin must be connected to Power Ground directly or through a sensing power resistor.
11	26	IN1 _B	Logic Input	Bridge B Input 1
12	27	IN2 _B	Logic Input	Bridge B Input 2
13	28	PROGCL _B	R Pin	Bridge B Overcurrent Level Programming. A resistor connected between this pin and Ground sets the programmable current limiting value for the bridge B. By connecting this pin to Ground the maximum current is set. This pin cannot be left non-connected.
14	29	EN _B	Logic Input	Bridge B Enable. LOW logic level switches OFF all Power MOSFETs of Bridge B. If not used, it has to be connected to +5V.
15	30	VBOOT	Supply Voltage	Bootstrap Voltage needed for driving the upper Power MOSFETs of both Bridge A and Bridge B.
16	32	OUT2 _B	Power Output	Bridge B Output 2.
17	33	VS _B	Power Supply	Bridge B Power Supply Voltage. It must be connected to the supply voltage together with pin VS _A .
20	4	VS _A	Power Supply	Bridge A Power Supply Voltage. It must be connected to the supply voltage together with pin VS _B .
21	5	OUT2 _A	Power Output	Bridge A Output 2.

PIN DESCRIPTION (continued)

PACKAGE		Name	Type	Function
SO24/ PowerDIP24	PowerSO36			
PIN #	PIN #			
22	7	VCP	Output	Charge Pump Oscillator Output.
23	8	EN _A	Logic Input	Bridge A Enable. LOW logic level switches OFF all Power MOSFETs of Bridge A. If not used, it has to be connected to +5V.
24	9	PROGCL _A	R Pin	Bridge A Overcurrent Level Programming. A resistor connected between this pin and Ground sets the programmable current limiting value for the bridge A. By connecting this pin to Ground the maximum current is set. This pin cannot be left non-connected.

ELECTRICAL CHARACTERISTICS

(T_{amb} = 25 °C, V_S = 48V, unless otherwise specified)

Symbol	Parameter	Test Conditions	Min	Typ	Max	Unit
V _{Sth(ON)}	Turn-on Threshold		6.6	7	7.4	V
V _{Sth(OFF)}	Turn-off Threshold		5.6	6	6.4	V
I _S	Quiescent Supply Current	All Bridges OFF; T _j = -25°C to 125°C ⁽⁶⁾		5	10	mA
T _{j(OFF)}	Thermal Shutdown Temperature			165		°C

Output DMOS Transistors

R _{DS(ON)}	High-Side Switch ON Resistance	T _j = 25 °C		0.34	0.4	Ω
		T _j = 125 °C ⁽⁶⁾		0.53	0.59	Ω
	Low-Side Switch ON Resistance	T _j = 25 °C		0.28	0.34	Ω
		T _j = 125 °C ⁽⁶⁾		0.47	0.53	Ω
I _{DSS}	Leakage Current	EN = Low; OUT = V _S			2	mA
		EN = Low; OUT = GND	-0.15			mA

Source Drain Diodes

V _{SD}	Forward ON Voltage	I _{SD} = 2.8A, EN = LOW		1.15	1.3	V
t _{rr}	Reverse Recovery Time	I _f = 2.8A		300		ns
t _{fr}	Forward Recovery Time			200		ns

Logic Input

V _{IL}	Low level logic input voltage		-0.3		0.8	V
V _{IH}	High level logic input voltage		2		7	V
I _{IL}	Low Level Logic Input Current	GND Logic Input Voltage	-10			μA

ELECTRICAL CHARACTERISTICS (continued)(T_{amb} = 25 °C, V_S = 48V, unless otherwise specified)

Symbol	Parameter	Test Conditions	Min	Typ	Max	Unit
I _{IH}	High Level Logic Input Current	7V Logic Input Voltage			10	μA
V _{th(ON)}	Turn-on Input Threshold			1.8	2.0	V
V _{th(OFF)}	Turn-off Input Threshold		0.8	1.3		V
V _{th(HYS)}	Input Threshold Hysteresis		0.25	0.5		V

Switching Characteristics

t _{D(on)EN}	Enable to out turn ON delay time ⁽⁷⁾	I _{LOAD} = 2.8A, Resistive Load	100	250	400	ns
t _{D(on)IN}	Input to out turn ON delay time	I _{LOAD} = 2.8A, Resistive Load (dead time included)		1.6		μs
t _{RISE}	Output rise time ⁽⁷⁾	I _{LOAD} = 2.8A, Resistive Load	40		250	ns
t _{D(off)EN}	Enable to out turn OFF delay time ⁽⁷⁾	I _{LOAD} = 2.8A, Resistive Load	300	550	800	ns
t _{D(off)IN}	Input to out turn OFF delay time	I _{LOAD} = 2.8A, Resistive Load		600		ns
t _{FALL}	Output Fall Time ⁽⁷⁾	I _{LOAD} = 2.8A, Resistive Load	40		250	ns
t _{dt}	Dead Time Protection		0.5	1		μs
f _{CP}	Charge pump frequency	-25°C < T _j < 125°C		0.6	1	MHz

Over Current Detection

I _{S over}	Input Supply Over Current Detection Threshold	-25°C < T _j < 125 °C; RCL= 39 kΩ -25°C < T _j < 125 °C; RCL= 5 kΩ -25°C < T _j < 125 °C; RCL= GND	-10% -10% -30%	0.57 4.42 5.6	+10% +10% +30%	A A A
R _{OPDR}	Open Drain ON Resistance	I = 4mA		40	60	Ω
t _{OCD(ON)}	OCD Turn-on Delay Time (8)	I = 4mA; C _{EN} < 100pF		200		ns
t _{OCD(OFF)}	OCD Turn-off Delay Time (8)	I = 4mA; C _{EN} < 100pF		100		ns

(6) Tested at 25°C in a restricted range and guaranteed by characterization.

(7) See Fig. 1.

(8) See Fig. 2.